NSN 5961-00-372-1816

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Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-372-1816 **Inclosure Material:** Plastic all transistor **Overall Length:** 0.170 inches all transistor and 0.210 inches all transistor **Terminal Length:** 0.500 inches all transistor **Internal Configuration:** Field effect all transistor **Channel Polarity And Control Type (non-core):** N-channel junction type all transistor Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source all transistor **Current Rating Per Characteristic:** 9.00 milliamperes zero-gate-voltage source current megawatts all transistor **Terminal Type And Quantity:** 3 uninsulated wire lead all transistor Shelf Life: N/a **Unit Of Measure: Demilitarization:** No